SCAS526A - AUGUST 1995 - REVISED APRIL 1996

- Inputs Are TTL-Voltage Compatible
- EPIC ™ (Enhanced-Performance Implanted CMOS) 1-µm Process
- Package Options Include Plastic Small-Outline (D), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages, Ceramic Chip Carriers (FK) and Flatpacks (W), and Standard Plastic (N) and Ceramic (J) DIPS

description

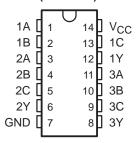
The 'ACT10 contain three independent 3-input NAND gates. The devices perform the Boolean functions $Y = \overline{A \cdot B \cdot C}$ or $Y = \overline{A} + \overline{B} + \overline{C}$ in positive logic.

The SN54ACT10 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74ACT10 is characterized for operation from -40°C to 85°C.

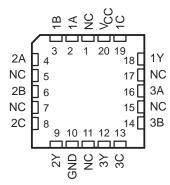
FUNCTION TABLE (each gate)

INPUTS			OUTPUT
Α	В	С	Y
Н	Н	Н	L
L	X	Χ	Н
Х	L	Χ	Н
Х	X	L	Н

SN54ACT10 . . . J OR W PACKAGE SN74ACT10 . . . D, DB, N, OR PW PACKAGE (TOP VIEW)

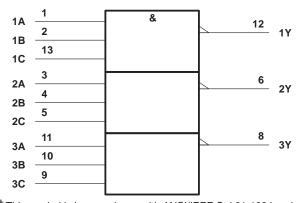


SN54ACT10 ... FK PACKAGE (TOP VIEW)



NC - No internal connection

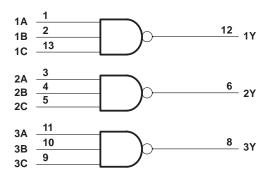
logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for the D, DB, J, N, PW, and W packages.

logic diagram, each gate (positive logic)





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SN54ACT10, SN74ACT10 TRIPLE 3-INPUT POSITIVE-NAND GATES

SCAS526A - AUGUST 1995 - REVISED APRIL 1996

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	
Input voltage range, V _I (see Note 1)	\dots -0.5 V to V _{CC} + 0.5 V
Output voltage range, VO (see Note 1)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$)	±20 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$)	±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	±50 mA
Continuous current through V _{CC} or GND	±200 mA
Maximum power dissipation at T _A = 55°C (in still air) (see Note 2	2): D package 1.25 W
	DB package 0.5 W
	N package 1.1 W
	PW package 0.5 W
Storage temperature range, T _{sto}	65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
 - 2. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils, except for the N package, which has a trace length of zero.

recommended operating conditions (see Note 3)

		SN54ACT10 MIN MAX		SN74ACT10		UNIT
				MIN	MAX	UNIT
VCC	Supply voltage	4.5	5.5	4.5	5.5	V
VIH	High-level input voltage	2		2		V
V _{IL}	Low-level input voltage		0.8		0.8	V
VI	Input voltage	0	Vcc	0	VCC	V
VO	Output voltage	0	VCC	0	VCC	V
lOH	High-level output current		-24		-24	mA
lOL	Low-level output current		24		24	mA
Δt/Δν	Input transition rise or fall rate	0	8	0	8	ns/V
TA	Operating free-air temperature	-55	125	-40	85	°C

NOTE 3: Unused inputs must be held high or low to prevent them from floating.



SN54ACT10, **SN74ACT10** TRIPLE 3-INPUT POSITIVE-NAND GATES

SCAS526A - AUGUST 1995 - REVISED APRIL 1996

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	vcc	T _A = 25°C			SN54ACT10		SN74ACT10		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
VOH	I _{OH} = - 50 μA	4.5 V	4.4	4.49		4.4		4.4		-
		5.5 V	5.4	5.49		5.4		5.4		
	I _{OH} = – 24 mA	4.5 V	3.86			3.7		3.76		V
	IOH = - 24 MA	5.5 V	4.86			4.7		4.76		\ \ \
	$I_{OH} = -50 \text{ mA}^{\dagger}$	5.5 V				3.85				
	I _{OH} = -75 mA [†]	5.5 V						3.85		
	I _{OL} = 50 μA	4.5 V		0.001	0.1		0.1		0.1	V
V.		5.5 V		0.001	0.1		0.1		0.1	
	I _{OL} = 24 mA	4.5 V			0.36		0.5		0.44	
VOL		5.5 V			0.36		0.5		0.44	
	I _{OL} = 50 mA [†]	5.5 V					1.65			
	I _{OL} = 75 mA [†]	5.5 V							1.65	
lį	$V_I = V_{CC}$ or GND	5.5 V			±0.1		±1		±1	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		80		40	μΑ
Δlcc [‡]	One input at 3.4 V, Other inputs at GND or V _{CC}	5.5 V		0.6			1.6		1.5	mA
Ci	V _I = V _{CC} or GND	5 V		2.6						рF

[†] Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V $\,\pm\,$ 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	то	T _A = 25°C			SN54ACT10		SN74ACT10		UNIT
		(OUTPUT)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
^t PLH	Any	V	1	6.5	9	1	10	1	10	ns
t _{PHL}		'	1	6.5	9	1	9.5	1	9.5	115

operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

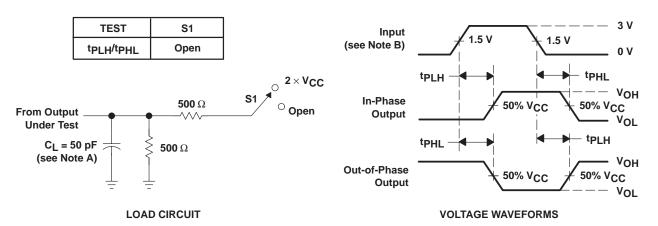
PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd} Power dissipation capacitance	$C_L = 50 \text{ pF}, f = 1 \text{ MHz}$	25	pF

[‡] This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

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SCAS526A - AUGUST 1995 - REVISED APRIL 1996

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_r \leq 2.5$ ns, $t_f \leq 2.5$ ns.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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